



ZXTP4003Z

100V PNP LED DRIVING TRANSISTOR IN SOT89

Features

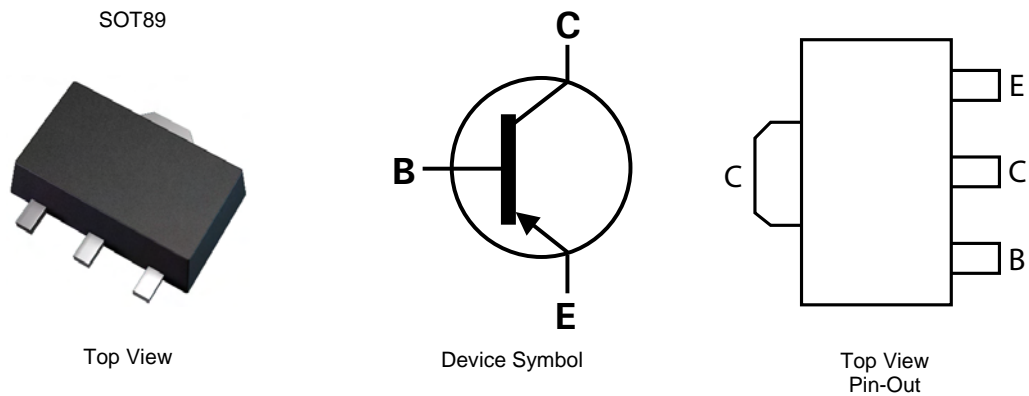
- $BV_{CEO} > -100V$
- Maximum continuous current $I_C = -1A$
- $h_{FE} > 100$ @ $I_C = -150mA$, $V_{CE} = -0.2V$
- **Lead Free, RoHS Compliant (Note 1)**
- **Halogen and Antimony Free "Green" Device (Note 2)**
- **Qualified to AEC-Q101 Standards for High Reliability**

Applications

- LED TV backlight

Mechanical Data

- Case: SOT89
- Case material: molded Plastic. "Green" molding Compound.
- UL Flammability Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Matte Tin Finish
- Weight: 0.052 grams (Approximate)

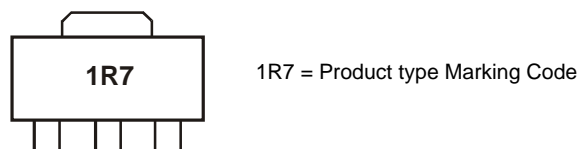


Ordering Information (Note 3)

Product	Marking	Reel size (inches)	Tape width (mm)	Quantity per reel
ZXTP4003ZTA	1R7	7	12	1000 units

- Notes:
1. No purposefully added lead.
 2. "Green" devices, Halogen and Antimony Free, Diodes Inc's "Green" Policy can be found on our website at <http://www.diodes.com>
 3. For Packaging Details, go to our website at <http://www.diodes.com>.

Marking Information



Maximum Ratings @ $T_A = 25^\circ\text{C}$ unless otherwise specified

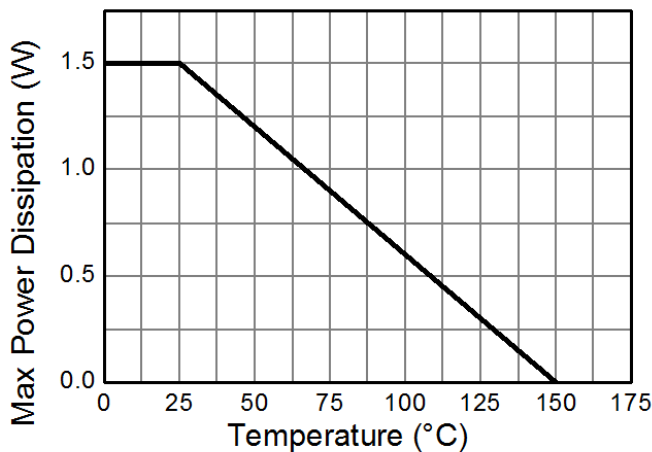
Characteristic	Symbol	Value	Unit
Collector-Base Voltage	V_{CBO}	-100	V
Collector-Emitter Voltage	V_{CEO}	-100	V
Emitter-Base Voltage	V_{EBO}	-7	V
Continuous Collector Current	I_C	-1	A
Peak Pulse Current (Note 4)	I_{CM}	-3	A
Base Current	I_B	-500	mA

Thermal Characteristics @ $T_A = 25^\circ\text{C}$ unless otherwise specified

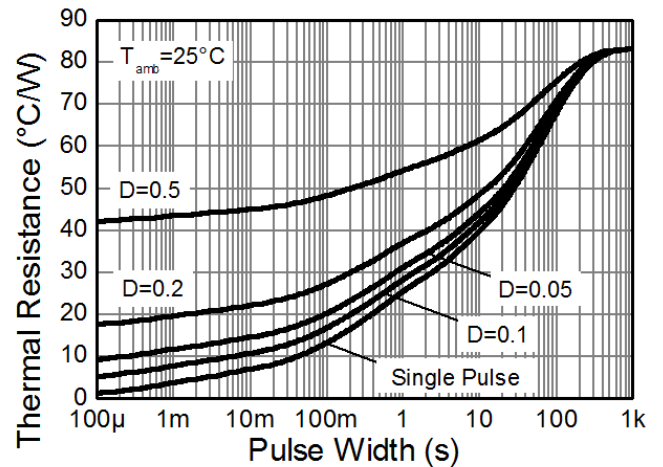
Characteristic	Symbol	Value	Unit
Power Dissipation (Note 5)	P_D	1.5	W
Thermal Resistance, Junction to Ambient (Note 5)	$R_{\theta JA}$	83	$^\circ\text{C/W}$
Thermal Resistance, Junction to Leads (Note 6)	$R_{\theta JL}$	17.46	$^\circ\text{C/W}$
Operating and Storage Temperature Range	T_J, T_{STG}	-55 to +150	$^\circ\text{C}$

- Notes:
4. Measured under pulsed conditions. Pulse width = 300 μs . Duty cycle $\leq 2\%$.
 5. For a device surface mounted on 25mm X 25mm FR4 PCB with high coverage of single sided 1 oz copper, in still air conditions
 6. Thermal resistance from junction to solder-point (on the exposed collector pad).

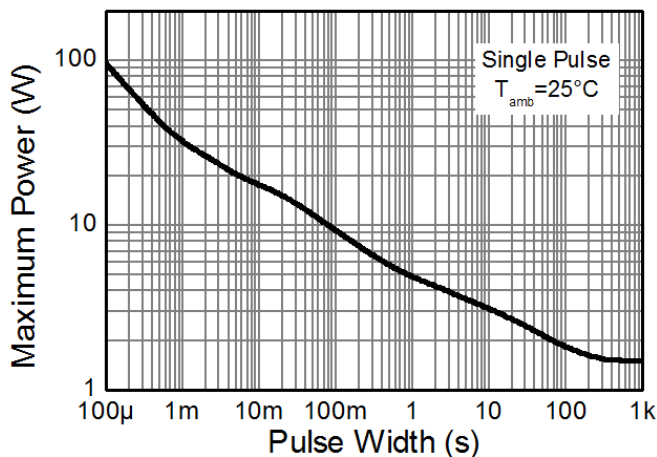
Thermal Characteristics and Derating Information



Derating Curve



Transient Thermal Impedance



Pulse Power Dissipation

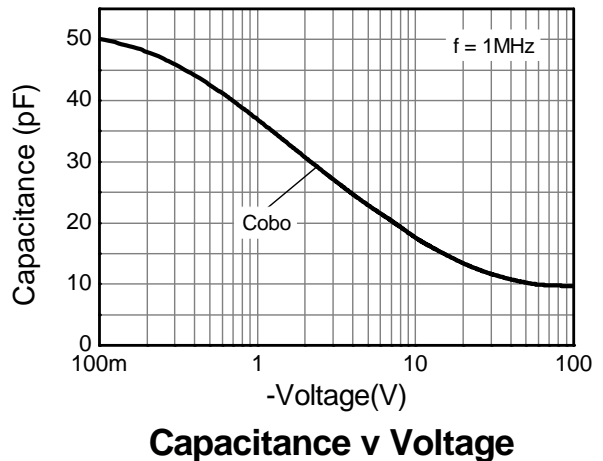
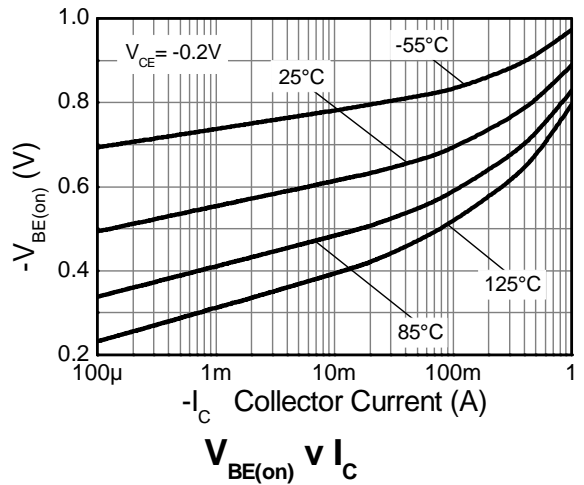
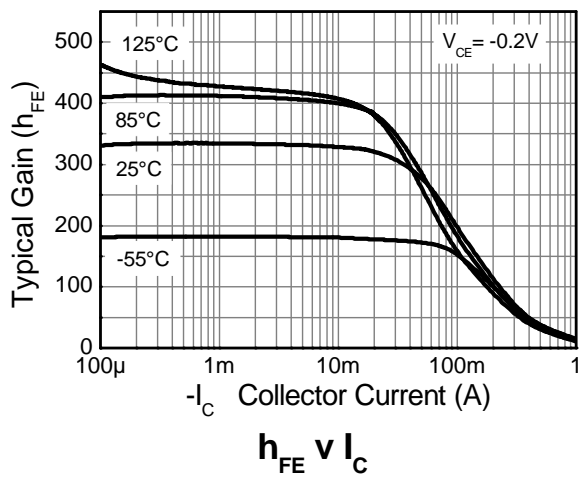
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Electrical Characteristics @ $T_A = 25^\circ\text{C}$ unless otherwise specified

Characteristic	Symbol	Min	Typ	Max	Unit	Test Condition
Collector-Emitter Breakdown Voltage (Note 7)	BV_{CEO}	-100	-170	-	V	$I_C = -10\text{mA}$
Collector Cut-off Current	I_{CBO}	-	-	-50	nA	$V_{CB} = -100\text{V}$
Emitter Cut-off Current	I_{EBO}	-	-	-50	nA	$V_{EB} = -7\text{V}$
Static Forward Current Transfer Ratio (Note 7)	h_{FE}	60 100	133 112	-	-	$I_C = -85\text{mA}, V_{CE} = -0.15\text{V}$ $I_C = -150\text{mA}, V_{CE} = -0.2\text{V}$
Base-Emitter Turn-On Voltage (Note 7)	$V_{BE(on)}$	-	-0.71	-0.95	V	$I_C = -150\text{mA}, V_{CE} = -0.2\text{V}$
Delay Time	$t_{(d)}$	-	378	-	ns	$V_{CC} = -80\text{V}, I_C = -150\text{mA}, f$ $-I_{B2} = 1.5\text{mA}, V_{CE(ON)} = -0.2\text{V}$
Rise Time	$t_{(r)}$	-	388	-	ns	
Storage Time	$t_{(s)}$	-	1348	-	ns	
Fall Time	$t_{(f)}$	-	382	-	ns	$V_{CC} = -80\text{V}, I_C = -150\text{mA},$ $-I_{B2} = -1.5\text{mA}, V_{CE(ON)} = -4\text{V}$
Storage Time	$t_{(s)}$	-	75	-	ns	
Fall Time	$t_{(f)}$	-	363	-	ns	

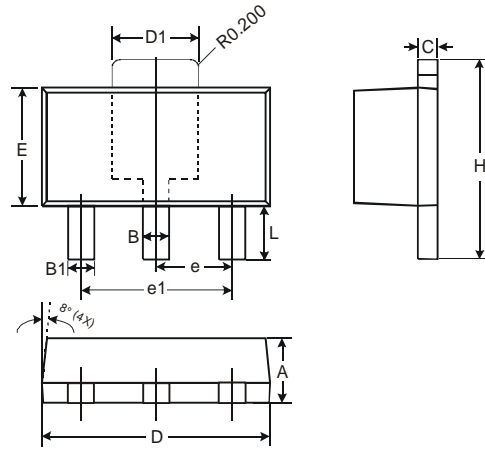
Notes: 7. Measured under pulsed conditions. Pulse width = 300 μs . Duty cycle $\leq 2\%$

Electrical Characteristics @ $T_A = 25^\circ\text{C}$ unless otherwise specified



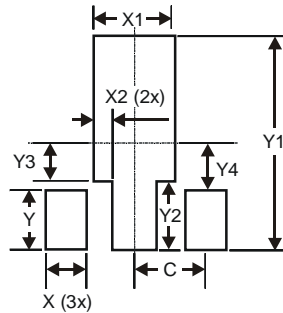
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Package Outline Dimensions



SOT89		
Dim	Min	Max
A	1.40	1.60
B	0.44	0.62
B1	0.35	0.54
C	0.35	0.43
D	4.40	4.60
D1	1.52	1.83
E	2.29	2.60
e	1.50 Typ	
e1	3.00 Typ	
H	3.94	4.25
L	0.89	1.20
All Dimensions in mm		

Suggested Pad Layout



Dimensions	Value (in mm)
X	0.900
X1	1.733
X2	0.416
Y	1.300
Y1	4.600
Y2	1.475
Y3	0.950
Y4	1.125
C	1.500

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